

L-band Phase Shifter

GaAs Monolithic Microwave IC in surface mount ceramic-metal package

Description

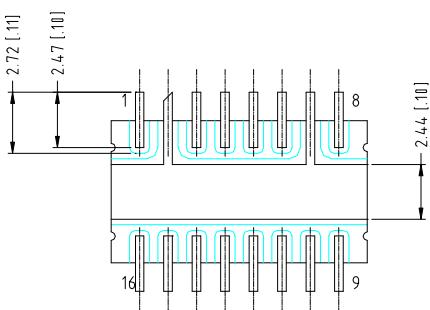
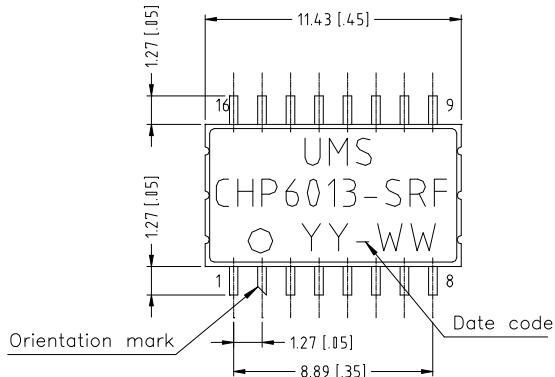
The CHP6013 is a L-band monolithic 6-bit phase shifter.

The circuit is manufactured with a standard $0.7\mu\text{m}$ MESFET process: via holes through the substrate, air bridges and electron beam gate lithography. It is supplied in surface mount ceramic-metal package

Main Features

- Frequency range : 1.2 to 1.4GHz
- 5.625° phase step
- 64 states
- 0/-6V control voltage
- Surface mount package
- dimension: $11.43 \times 8.89 \times 1.9 \text{ mm}^3$

Surface mount ceramic-metal package :



Electrical Characteristics

- Tamb = +25°C
- Test conditions: Pin ≤ 0dBm, Low level control voltage = -6V, High level control voltage = 0V
- Specifications for the main bit states: 0, 1, 2, 4, 8, 16, 32 and 63

Symbol	Parameter	Min	Max	Unit
Fop	Operating frequency range	1.2	1.4	GHz
AV	Amplitude variation		± 1	dB
PPE	Peak Phase Error		± 5	°
IL	Insertion loss		8.5	dB
ILm	Insertion loss match at state 0 unit to unit (1)		± 0.25	dB
Ipm	Insertion phase match at state 0 unit to unit (1)		± 7	°
VSWRin	Input VSWR		2:1	
VSWRout	Output VSWR		2.3:1	

(1) Average value defined by production lot.

ESD Protections : Electrostatic discharge sensitive device observe handling precautions !

Peak Phase Error (PPE) definition:

PPE(i)=measured_phase(S21)@state(i) – measured_phase(S21)@state(0) – theoretical_phase value@state(i)

(i) = 0, 1, 2, 4, 8, 16, 32, 63 = main bit states.

Amplitude variation (AV) definition:

AV(i) = measured_dB(S21)@state(i) – measured_dB(S21)@state(0)

(i) = 0, 1, 2, 4, 8, 16, 32, 63 = main bit states.

Absolute Maximum Ratings

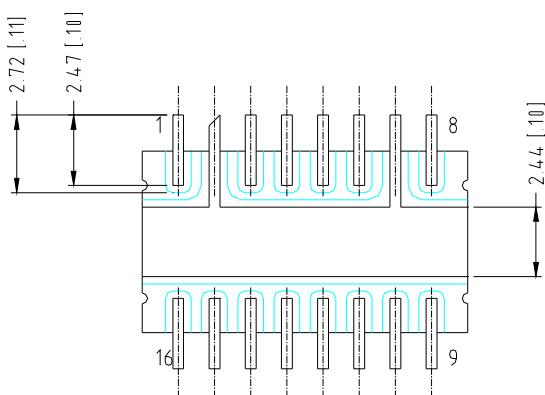
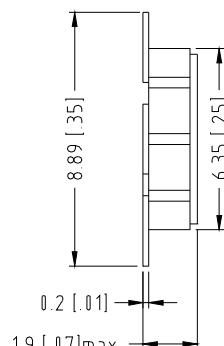
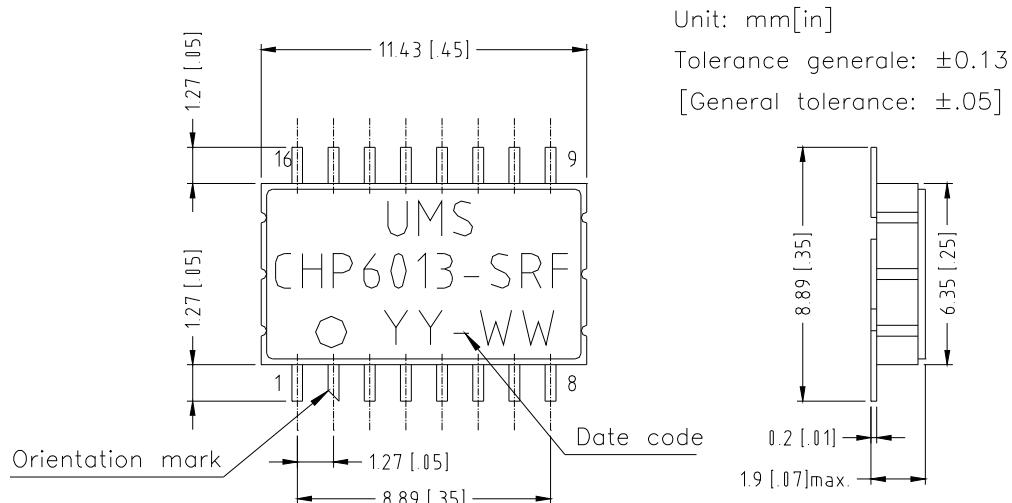
Tamb = +25°C

Operation of this device above anyone of these parameters may cause permanent damage.

Symbol	Parameter	Values	Unit
Vgi	Phase shifter control voltage	-7.5	V
Pin	Maximum peak input power overdrive (1)	+30	dBm
Top	Operating temperature range	-40 to +85	°C
Tstg	Storage temperature range	-55 to +125	°C

(1) Duration < 1s.

Package information



Pin	Function	Pin	Function
1	RF in	9	H11
2	Gnd	10	B11
3	H22	11	H180
4	B22	12	B180
5	B5	13	B45
6	H5	14	H45
7	Gnd	15	H90
8	RF out	16	B90

Ordering Information

Package form : CHP6013-SRF/23

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